Low Capacitance Transient Voltage Suppressor Array

This integrated transient voltage suppressor device (TVS) is designed for applications requiring transient overvoltage protection. It is intended for use in sensitive equipment such as computers, printers, business machines, communication systems, medical equipment, and other applications. Its integrated design provides very effective and reliable protection for eight separate lines using only one package. These devices are ideal for situations where board space is at a premium.

Features

- Low Capacitance
- Low Leakage Current < 1 μA @ 3 V
- ESD Ratings:
 - IEC61000-4-2, 18 kV (Contact)
 - IEC61000-4-2, 30 kV (Air)
 - Machine Model = Class C, 400 V
 - ◆ Human Body Model = Class 3B, 8 kV
- DFN Package, 1.6 x 1.6 mm
- Moisture Sensitivity Level 1
- This is a Pb-Free Device

Benefits

- Provides Protection for ESD Industry Standards: IEC 61000, HBM
- Protects the Line Against Transient Voltage Conditions in Either Direction
- Minimize Power Consumption of the System
- Minimize PCB Board Space

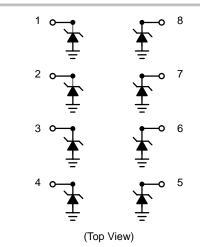
Applications

- ESD Protection for Data Lines
- Wireless Phones
- Handheld Products
- Notebook Computers
- LCD Displays



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DFN8 CASE 506AK



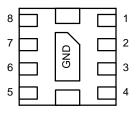
5S = Specific Device Code

M = Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

PIN CONNECTIONS



(Bottom View)

ORDERING INFORMATION

Device	Package	Shipping [†]				
NUP8028MNT1G	DFN8 (Pb-Free)	3000 / Tape & Reel				

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
ESD Discharge IEC61000-4-2 Air Discharge Contact Discharge	V _{PP}	15 8.0	kV
Peak Power Dissipation (8 x 20 μS @ T _A = 25°C)	P _{pk} (Note 1)	20	W
Operating Temperature Range	T _{OP}	-40 to 85	°C
Storage Temperature Range	T _{STG}	-55 to 150	°C
Maximum Lead Temperature for Soldering Purposes (1.8 in from case for 10 seconds)	T _L	260	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise noted)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Maximum Reverse Working Voltage	V_{RWM}				3.0	V
Breakdown Voltage	V_{BR}	$I_R = 1.0 \text{ mA}$	5.3	5.6	5.9	V
Leakage Current	I _R	V _{RWM} = 3.3 V		0.01	1.0	μΑ
Clamping Voltage	V _c	I _{PP} = 1.6 A			13	V
Capacitance	C _d	$f = 1 MHz, V_R = 0 V$		13	17	pF
Capacitance	C _d	$f = 1 MHz, V_R = 3.0 V$		7.0	11.5	pF

^{1.} Nonrepetitive current per Figure 4.

TYPICAL PERFORMANCE CURVES (T_A= 25°C unless otherwise specified)

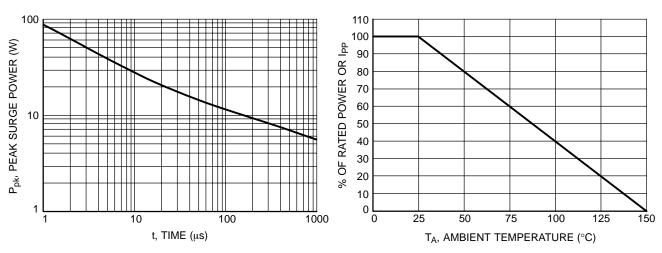


Figure 1. Pulse Width

Figure 2. Power Derating Curve

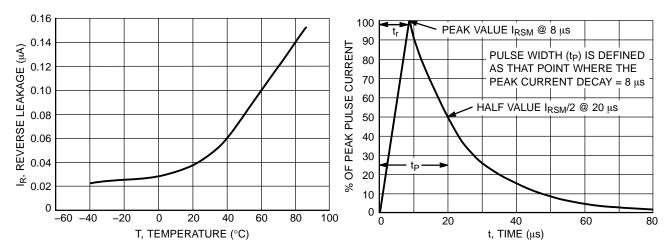


Figure 3. Reverse Leakage versus Temperature

Figure 4. $8 \times 20 \mu s$ Pulse Waveform

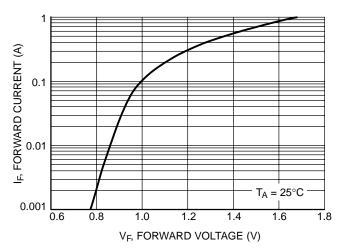
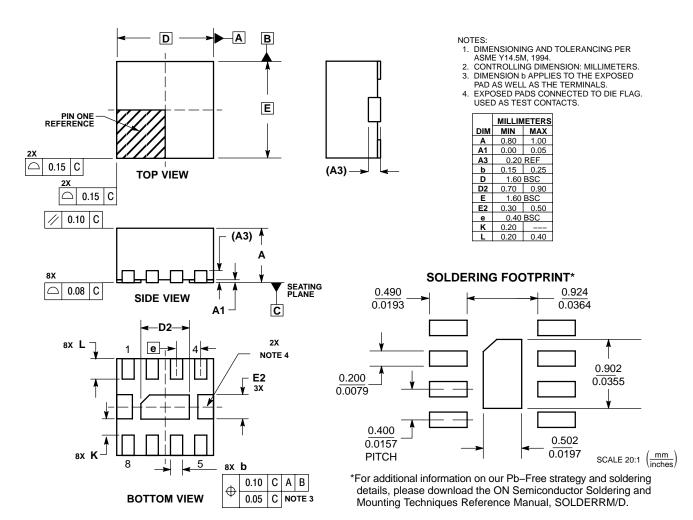


Figure 5. Forward Voltage

PACKAGE DIMENSIONS

DFN8 CASE 506AK-01 ISSUE C



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